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Kind regards,

Team Nexperia

**30 V, 100 mA NPN general-purpose transistors** Rev. 07 — 17 November 2009 P

Product data sheet

#### 1. **Product profile**

#### 1.1 General description

NPN general-purpose transistors in Surface Mounted Device (SMD) plastic packages.

Table 1. Prod	uct overview			
Type number	Package	Package		
	NXP	JEITA	JEDEC	complement
BC848B	SOT23	-	TO-236AB	BC858B
BC848W	SOT323	SC-70	-	BC858W

#### **1.2 Features**

- General-purpose transistors
- SMD plastic packages

#### **1.3 Applications**

General-purpose switching and amplification

### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	30	V
I <sub>C</sub>	collector current		-	-	100	mA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 2 mA				
	BC848B		200	290	450	
	BC848W		110	-	800	



30 V, 100 mA NPN general-purpose transistors

### 2. Pinning information

Table 3.	Pinning	
Pin	Description	Simplified outline Symbol
1	base	
2	emitter	
3	collector	1 2 006aaa144 sym021

### 3. Ordering information

Table 4. Ordering information					
Type number	Package				
	Name	Description	Version		
BC848B	-	plastic surface mounted package; 3 leads	SOT23		
BC848W	SC-70	plastic surface mounted package; 3 leads	SOT323		

### 4. Marking

Table 5. Marking codes	
Type number	Marking code <sup>[1]</sup>
BC848B	1K*
BC848W	1M*

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

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### 5. Limiting values

Table 6. In accordar	Limiting values nce with the Absolute Maximu	ım Rating System (I	EC 60134).		
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	30	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	30	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current		-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \leq 1 ms$	-	200	mA
I <sub>BM</sub>	peak base current	single pulse; $t_p \leq 1 \text{ ms}$	-	200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u>		
	SOT23		-	250	mW
	SOT323		-	200	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

### 6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	SOT23		-	-	500	K/W
	SOT323		-	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

30 V, 100 mA NPN general-purpose transistors

### 7. Characteristics

<b>Table 8.</b> T <sub>amb</sub> = 25	Characteristics 5 ℃ unless otherwise s	pecified.					
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = 30 \text{ V}; \text{ I}_{E} = 0 \text{ A}$		-	-	15	nA
	current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$		-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 5 V; $I_C$ = 10 $\mu$ A		-	150	-	
		$V_{CE}$ = 5 V; $I_C$ = 2 mA					
		BC848B		200	290	450	
		BC848W		110	-	800	
V <sub>CEsat</sub>	collector-emitter	$I_{C} = 10 \text{ mA}; I_{B} = 0.5 \text{ mA}$		-	90	250	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	<u>[1]</u>	-	200	600	mV
V <sub>BEsat</sub>	base-emitter	$I_{C} = 10 \text{ mA}; I_{B} = 0.5 \text{ mA}$	[2]	-	700	-	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[2]	-	900	-	mV
$V_{BE}$	base-emitter voltage	$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$	[3]	580	660	700	mV
		$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	[3]	-	-	770	mV
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA};$ f = 100 MHz		100	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A};$ f = 1 MHz		-	2.5	3	pF
NF	noise figure			-	2	10	dB

 $\label{eq:point} \begin{tabular}{ll} \begin{$ 

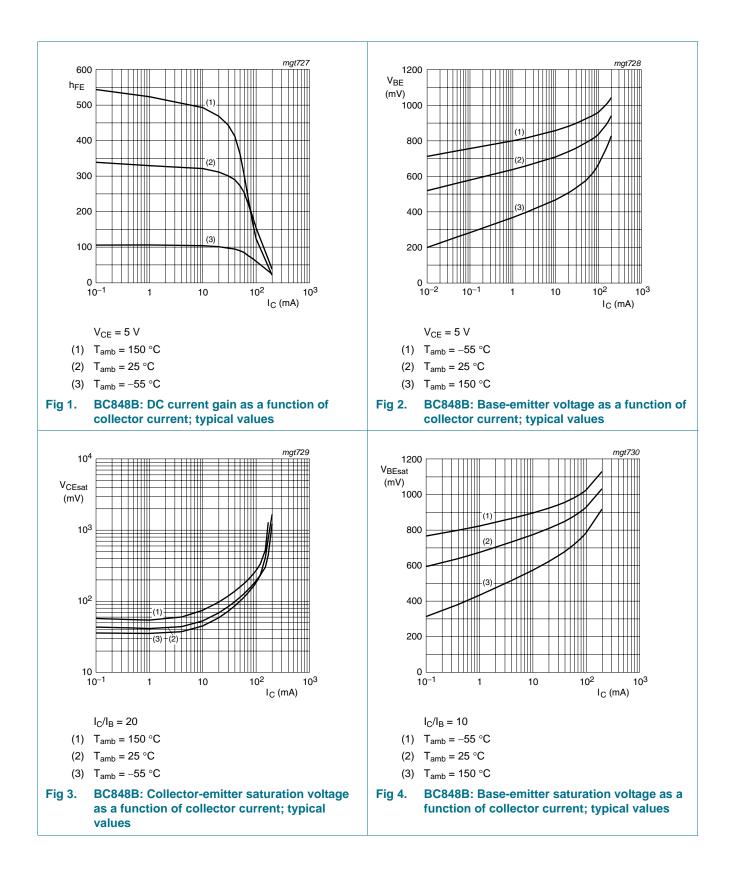
[2] V<sub>BEsat</sub> decreases by approximately 1.7 mV/K with increasing temperature.

[3] V<sub>BE</sub> decreases by approximately 2 mV/K with increasing temperature.

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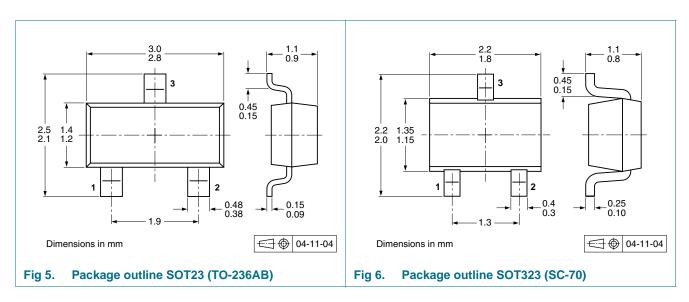
### **BC848 series**

30 V, 100 mA NPN general-purpose transistors



30 V, 100 mA NPN general-purpose transistors

### 8. Package outline



### 9. Packing information

#### Table 9.Packing methods

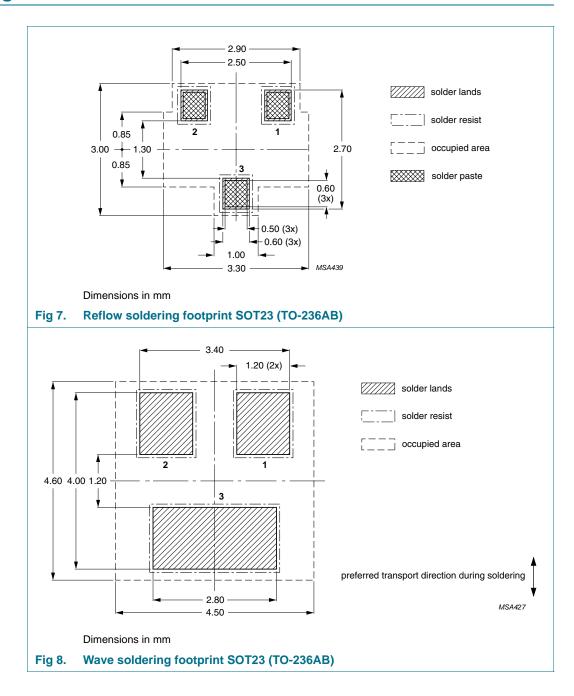
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Imber Package Description		Packing quantity		
			3000	10000	
BC848B	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235	
BC848W	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135	

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

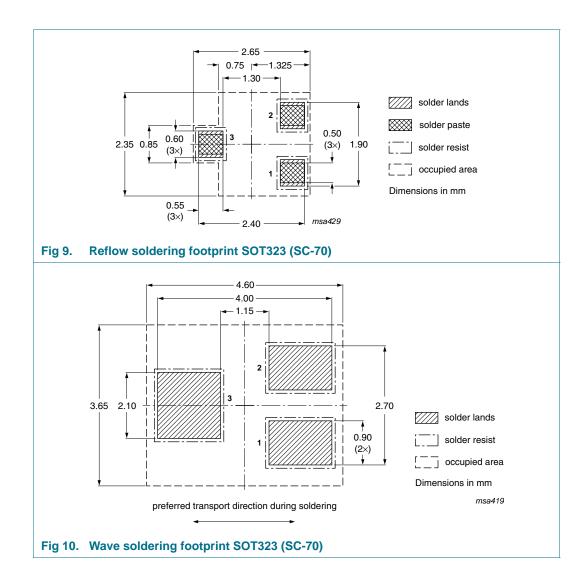
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### 10. Soldering



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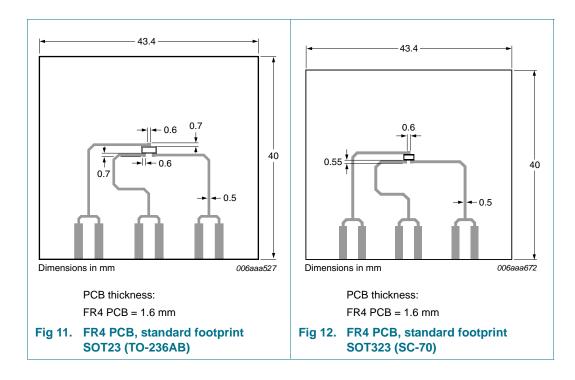


BC848\_SER\_7

Product data sheet

30 V, 100 mA NPN general-purpose transistors

### 11. Mounting



BC848\_SER\_7

Product data sheet

30 V, 100 mA NPN general-purpose transistors

### **12. Revision history**

Table 10. Revision histo	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BC848_SER_7	20091117	Product data sheet	-	BC848_SER_6
Modifications:		was changed to reflect the egal definitions and disclain		
	Figure 9 "Reflow	w soldering footprint SOT32	23 (SC-70)": updated	
	Figure 10 "Wav	e soldering footprint SOT32	23 (SC-70)": updated	
BC848_SER_6	20060203	Product data sheet	-	BC846_BC847_ BC848_5 BC846W_BC847W_ BC848W_4
BC846_BC847_BC848_5	20040206	Product specification	-	BC846_BC847_ BC848_4
BC846W_BC847W_ BC848W_4	20020204	Product specification	-	BC846W_847W_3

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### 13. Legal information

#### Data sheet status 13.1

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

The term 'short data sheet' is explained in section "Definitions". [2]

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://w

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### **BC848** series

30 V, 100 mA NPN general-purpose transistors

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